# NSN 5961-00-857-3263

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# Inclosure Material:

Metal

# **Overall Length:**

Between 0.250 inches and 0.340 inches

# **Overall Diameter:**

Between 0.470 inches and 0.500 inches

# **Mounting Facility Quantity:**

2

## **Internal Configuration:**

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

## **Mounting Method:**

Unthreaded hole

Features Provided:

#### Hermetically sealed case

Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

375.0 breakdown voltage, collector-to-base, emitter open and 250.0 breakdown voltage, collector-to-emitter, base open and 6.0

breakdown voltage, emitter-to-base, collector open

# **Current Rating Per Characteristic:**

2.00 amperes source cutoff current and 1.00 amperes source cutoff current

## Power Rating Per Characteristic:

35.0 watts small-signal input power, common-collector

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

## **Special Features:**

Junction pattern arrangement: npn

## **Terminal Type And Quantity:**

2 uninsulated wire lead and 1 case

Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

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